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BIB DATA SHEET

CONFIRMATION NO. 9501

APPLICANTS Masaru Sasaki, Hyogo-ken, JAPAN; Yoshiro Kabe, Hyogo-ken, JAPAN; *** CONTINUING DATA ***************************** This application is a 371 of PCT/JP04/02488 03/01/2004 *** FOREIGN APPLICATIONS ************************************	SERIAL NUM	IBER FILING	or_371(c)		CLASS	GROUP AR	OUP ART UNIT		ATTORNEY DOCKET	
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35 USC 119(a-d) conditions met Yes No Verified and Acknowledged / Examiner's Signature Initials ADDRESS CLAIMS C										
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OBLON, SPIVAK, MCCLELLAND MAIER & NEUSTADT, L.L.P. 1940 DUKE STREET ALEXANDRIA, VA 22314 UNITED STATES										
TITLE	TITLE									
Method for Manufacturing Semiconductor Device and Plasma Oxidation Method	Method fo	or Manufacturing S	emiconduct	tor Dev	ice and Plasma (Oxidation Met	nod			
☐ All Fees		EFFC: Authority has been siven in Daner					☐ All Fees			
□ 1.16 Fees (Filing)							☐ 1.16 Fees (Filing)			
FILING FEE No to charge/credit DEPOSIT ACCOUNT		FEES: Authority has been given in Paper No. to charge/credit DEPOSIT ACCOUNT				NT 1.17	☐ 1.17 Fees (Processing Ext. of time)			
900 No for following:	0						☐ 1.18 Fees (Issue)			
☐ Other							Other			
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